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FDP8442-F085

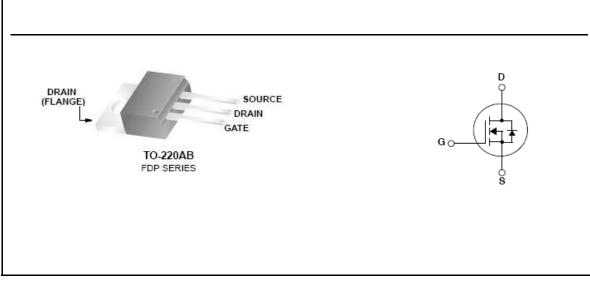
N-Channel PowerTrench[®] MOSFET 40V, 80A, $3.1m\Omega$

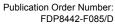
Features

- Typ $r_{DS(on)} = 2.3m\Omega$ at $V_{GS} = 10V$, $I_D = 80A$
- Typ Q_{g(10)} = 181nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems





Symbol	Parameter								Ratings		
V _{DSS}	Drain to Source Voltage								40		
V _{GS}	Gate to Source Voltage								±20		
	Drain Current Continuous (T _C <158°C, V _{GS} = 10V)							80			
I _D	Drain Current Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta,JA} = 62^{\circ}C/W$)							23			А
	Pulsed							See Figure 4			
E _{AS}	Single Pulse Avalanche Energy (Not								720		mJ
в	Power Dis	sipation				254			W		
P _D	Derate above 25°C								1.7		
T _J , T _{STG}	Operating	and Storage Temp	erature				-55 to +175			°C	
Therm	al Cha	racteristics									
$R_{\theta JC}$	Thermal Resistance Junction to Case								0.59		
$R_{\theta,JA}$	Thermal Resistance Junction to Ambient				(Note 2)			62			°C/W
Packa	ge Mar	king and Or	dering I	nfori	nation						
Device	Device Marking Device Pac		Packag	ige Reel Size 1		Тар	Tape Width		Quantity		
FDF	FDP8442 FDP8442-F085 TO-220				AB Tube			N/A		50 units	
Electri	cal Cha	aracteristics	T _J = 25°C (unless	otherwise i	noted					
Symbol				Test Conditions				Min	Тур	Max	Units
Off Cha	racterist	ics									
B _{VDSS}	Drain to So	Drain to Source Breakdown Voltage		$I_{D} = 250 \mu A, V_{GS} = 0 V$				40	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current			$V_{DS} = 32V$ $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			-	-	1	μA	
	-		°C			-	-	250			
I _{GSS}	Gate to Sc	urce Leakage Curr	ent	V _{GS} =	±20V			-	-	±100	nA
On Cha	racterist	ics									
V _{GS(th)}	Gate to Source Threshold Voltage		$V_{DS} = V_{GS}, I_{D} = 250 \mu A$				2	2.9	4	V	
GO (11)	Drain to Source On Resistance			$\begin{split} I_{D} &= 80 \text{A}, \ V_{GS} = 10 \text{V} \\ I_{D} &= 80 \text{A}, \ V_{GS} = 10 \text{V}, \\ T_{J} &= 175^{\circ} \text{C} \end{split}$				-	2.3	3.1	
r _{DS(on)}							-	3.9	5.3	mΩ	
Dynami	c Charao	cteristics									
C _{iss}	Input Capacitance			V _{DS} = 25V, V _{GS} = 0V, f = 1MHz				-	12200	-	pF
C _{oss}	Output Capacitance Reverse Transfer Capacitance						-	1040	-	pF	
C _{rss}			-				640	-	pF		
R _G	Gate Resistance		V _{GS} = 0.5V, f = 1MHz				-	1.0	-	Ω	
Q _{g(TOT)}	Total Gate Charge at 10V			$V_{GS} = 0$ to 10V				-	181	235	nC
Q _{g(TH)}	Threshold	Gate Charge			0 to 2V	V _{DD} = 20	v	-	23	30	nC
Q _{gs}	Gate to Source Gate Charge			$I_D = 80A$				-	49	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		iteau	I _g = 1mA				-	26	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			1					41		nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switchi	ng Characteristics					
t _(on)	Turn-On Time		-	-	62	ns
t _{d(on)}	Turn-On Delay Time	V _{DD} = 20V, I _D = 80A V _{GS} = 10V, R _{GS} = 2Ω	-	19.5	-	ns
t _r	Turn-On Rise Time		-	19.3	-	ns
t _{d(off)}	Turn-Off Delay Time		-	57	-	ns
t _f	Turn-Off Fall Time		-	17.2	-	ns
t _{off}	Turn-Off Time		-	-	118	ns
t _f t _{off}	Turn-Off Time		-		- 118	
rain-S	ource Diode Characteristics					
V _{SD}	Course to Ducin Diada Maltana	I _{SD} = 80A	-	0.9	1.25	V
	Source to Drain Diode Voltage	I _{SD} = 40A	-	0.8	1.0	v

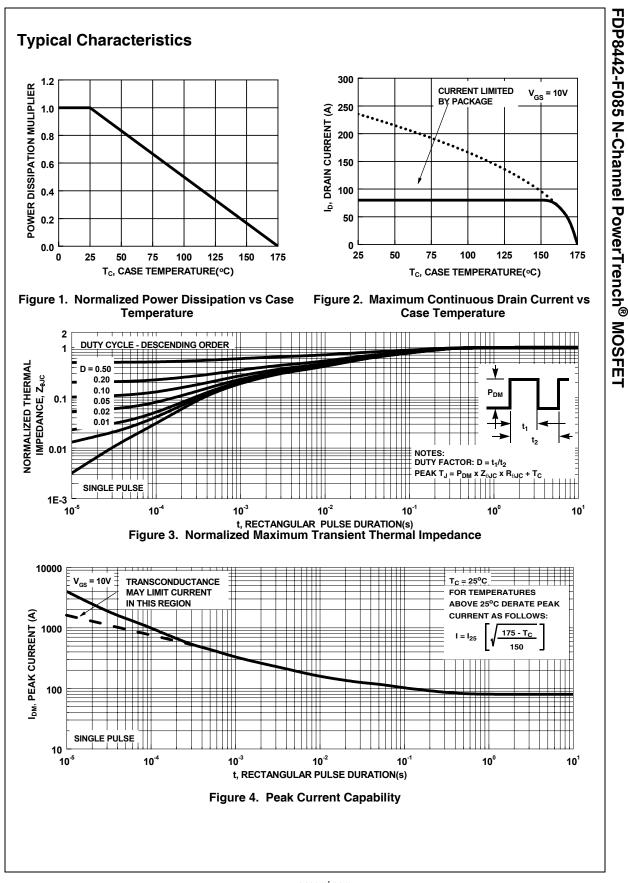
I_F = 75A, di/dt = 100A/μs Reverse Recovery Time 49 64 t_{rr} Qrr Reverse Recovery Charge I_F = 75A, di/dt = 100A/μs 70 91

Notes: 1: Starting $T_J = 25^{\circ}C$, L = 0.35mH, I_{AS} = 64A 2: Pulse width = 100s.

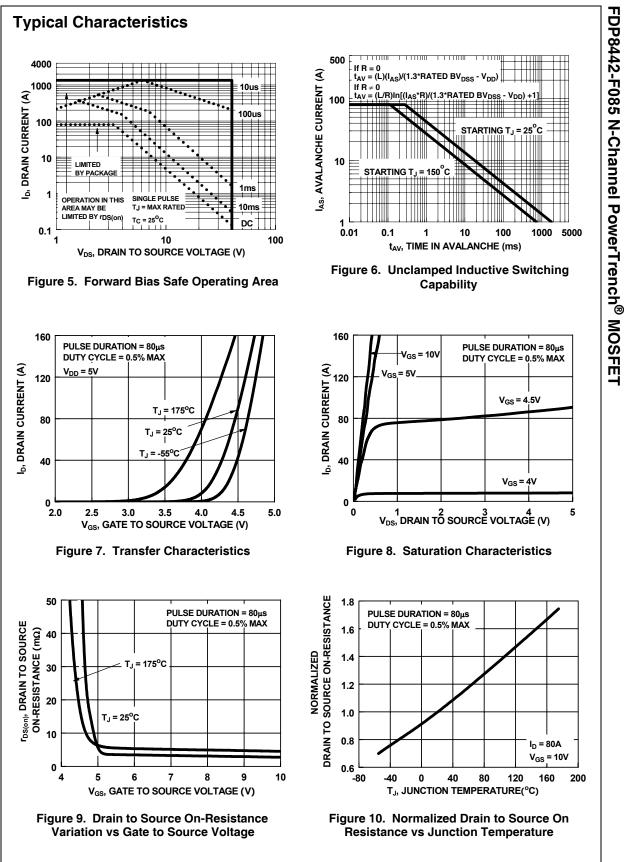
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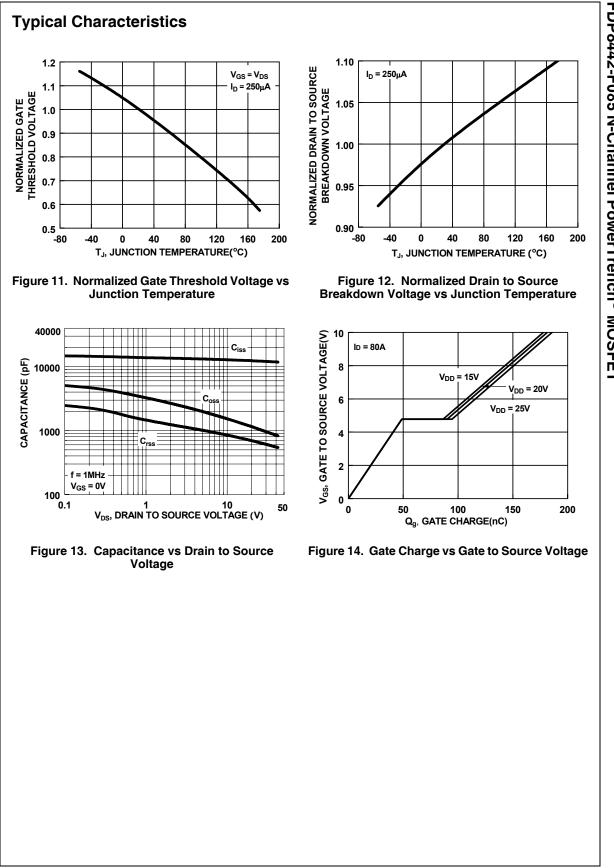
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